

LM136-2.5/LM236-2.5/LM336-2.5V Reference Diode

General Description

The LM136-2.5/LM236-2.5 and LM336-2.5 integrated circuits are precision 2.5V shunt regulator diodes. These monolithic IC voltage references operate as a low-temperature-coefficient 2.5V zener with 0.2 Ω dynamic impedance. A third terminal on the LM136-2.5 allows the reference voltage and temperature coefficient to be trimmed easily.

The LM136-2.5 series is useful as a precision 2.5V low voltage reference for digital voltmeters, power supplies or op amp circuitry. The 2.5V make it convenient to obtain a stable reference from 5V logic supplies. Further, since the LM136-2.5 operates as a shunt regulator, it can be used as either a positive or negative voltage reference.

The LM136-2.5 is rated for operation over -55° C to $+125^{\circ}$ C while the LM236-2.5 is rated over a -25° C to $+85^{\circ}$ C temperature range.

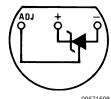
The LM336-2.5 is rated for operation over a 0°C to +70°C temperature range. See the connection diagrams for available packages.

Features

- Low temperature coefficient
- Wide operating current of 400 µA to 10 mA
- 0.2Ω dynamic impedance
- ±1% initial tolerance available
- Guaranteed temperature stability
- Easily trimmed for minimum temperature drift
- Fast turn-on

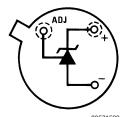
Connection Diagrams

TO-92
Plastic Package

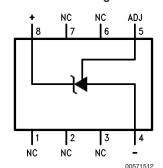


Bottom View
Order Number LM336Z-2.5 or LM336BZ-2.5
See NS Package Number Z03A

TO-46 Metal Can Package



Bottom View Order Number LM136H-2.5, LM136H-2.5/883, LM236H-2.5, or LM236AH-2.5 See NS Package Number H03H

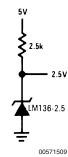


SO Package

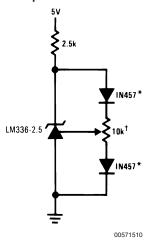
Top View
Order Number LM236M-2.5,
LM236AM-2.5, LM336M-2.5
or LM336BM-2.5
See NS Package Number M08A

Typical Applications

2.5V Reference

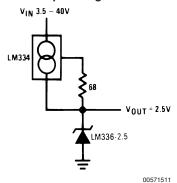


2.5V Reference with Minimum Temperature Coefficient



 † Adjust to 2.490V

Wide Input Range Reference



^{*}Any silicon signal diode

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current 15 mA Forward Current 10 mA Storage Temperature -60° C to $+150^{\circ}$ C

Operating Temperature Range (Note 2)

 LM336 0° C to +70 $^{\circ}$ C

Soldering Information

TO-92 Package (10 sec.) 260°C TO-46 Package (10 sec.) 300°C

SO Package

Vapor Phase (60 sec.) 215°C Infrared (15 sec.) 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" (Appendix D) for other methods of soldering surface mount devices.

Electrical Characteristics (Note 3)

		LM136A-2	2.5/LM236	4-2.5	LM	M336B-2.5		
Parameter	Conditions	Conditions LM136-2.5/LM236-2.5			LM336-2.5			Units
		Min	Тур	Max	Min	Тур	Max	
Reverse Breakdown	T _A =25°C, I _R =1 mA							
Voltage								
	LM136, LM236, LM336	2.440	2.490	2.540	2.390	2.490 2	.590	V
	LM136A, LM236A, LM336B	2.465	2.490	2.515	2.440	2.490 2	.540	V
Reverse Breakdown	T _A =25°C,		2.6	6		2.6	10	mV
Change								
With Current	400 μA≤I _R ≤10 mA							
Reverse Dynamic	$T_A = 25^{\circ}C$, $I_R = 1$ mA, $f = 100$ Hz		0.2	0.6		0.2	1	Ω
Impedance								
Temperature Stability	V _R Adjusted to 2.490V							
(Note 4)	I _R =1 mA, <i>Figure 2</i>							
	0°C≤T _A ≤70°C (LM336)					1.8	6	mV
	–25°C≤T _A ≤+85°C		3.5	9				mV
	(LM236H, LM236Z)							
	$-25^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C} \text{ (LM236M)}$		7.5	18				mV
	-55°C≤T _A ≤+125°C (LM136)		12	18				mV
Reverse Breakdown	400 μA≤I _B ≤10 mA		3	10		3	12	mV
Change								
With Current								
Reverse Dynamic	I _R =1 mA		0.4	1		0.4	1.4	Ω
Impedance								
Long Term Stability	T _A =25°C ±0.1°C, I _R =1 mA,		20			20		ppm
	t = 1000 hrs							

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its specified operating conditions.

Note 2: For elevated temperature operation, \boldsymbol{T}_{j} max is:

LM136 150°C LM236 125°C LM336 100°C

Thermal Resistance	TO-92	TO-46	SO-8	
θ_{ja} (Junction to Ambient)	180°C/W (0.4" leads)	440°C/W	165°C/W	
	170°C/W (0.125" lead)			
θ_{ja} (Junction to Case)	n/a	80°C/W	n/a	

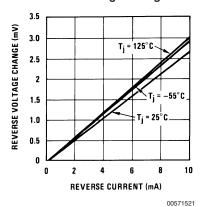
Electrical Characteristics (Note 3) (Continued)

Note 3: Unless otherwise specified, the LM136-2.5 is specified from $-55^{\circ}C \le T_{A} \le +125^{\circ}C$, the LM236-2.5 from $-25^{\circ}C \le T_{A} \le +85^{\circ}C$ and the LM336-2.5 from $0^{\circ}C \le T_{A} \le +70^{\circ}C$.

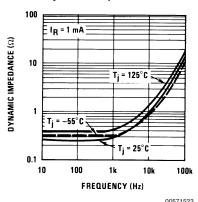
Note 4: Temperature stability for the LM336 and LM236 family is guaranteed by design. Design limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels. Stability is defined as the maximum change in V_{ref} from 25°C to T_A (min) or T_A (max).

Typical Performance Characteristics

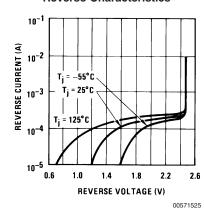
Reverse Voltage Change



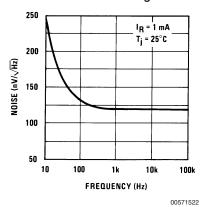
Dynamic Impedance



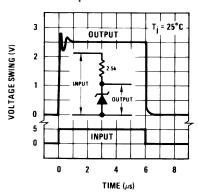
Reverse Characteristics



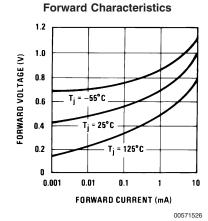
Zener Noise Voltage



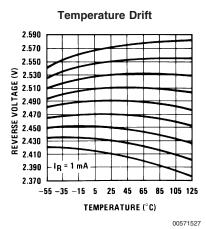
Response Time



00571524



Typical Performance Characteristics (Continued)



Application Hints

The LM136 series voltage references are much easier to use than ordinary zener diodes. Their low impedance and wide operating current range simplify biasing in almost any circuit. Further, either the breakdown voltage or the temperature coefficient can be adjusted to optimize circuit performance.

Figure 1 shows an LM136 with a 10k potentiometer for adjusting the reverse breakdown voltage. With the addition of R1 the breakdown voltage can be adjusted without affecting the temperature coefficient of the device. The adjustment range is usually sufficient to adjust for both the initial device tolerance and inaccuracies in buffer circuitry.

If minimum temperature coefficient is desired, two diodes can be added in series with the adjustment potentiometer as shown in *Figure 2*. When the device is adjusted to 2.490V the temperature coefficient is minimized. Almost any silicon signal diode can be used for this purpose such as a 1N914, 1N4148 or a 1N457. For proper temperature compensation the diodes should be in the same thermal environment as the LM136. It is usually sufficient to mount the diodes near the LM136 on the printed circuit board. The absolute resistance of R1 is not critical and any value from 2k to 20k will work.

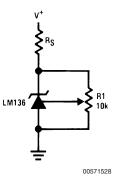


FIGURE 1. LM136 With Pot for Adjustment of Breakdown Voltage (Trim Range = ±120 mV typical)

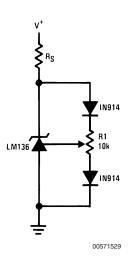
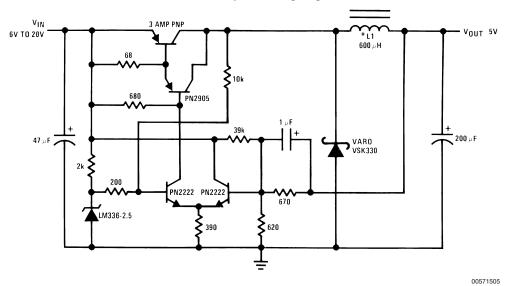


FIGURE 2. Temperature Coefficient Adjustment (Trim Range = ±70 mV typical)

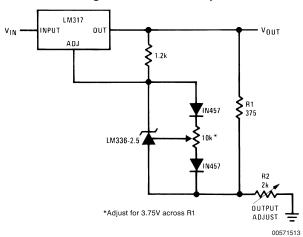
Application Hints (Continued)

Low Cost 2 Amp Switching Regulator[†]

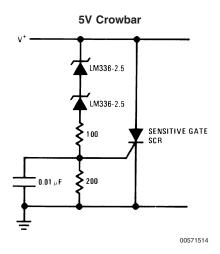


^{*}L1 60 turns #16 wire on Arnold Core A-254168-2

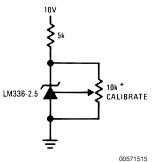
Precision Power Regulator with Low Temperature Coefficient



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Trimmed 2.5V Reference with Temperature Coefficient Independent of Breakdown Voltage

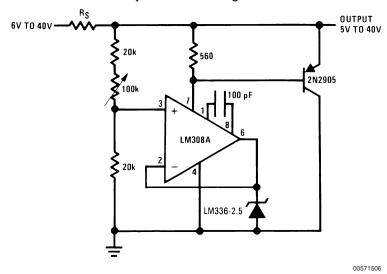


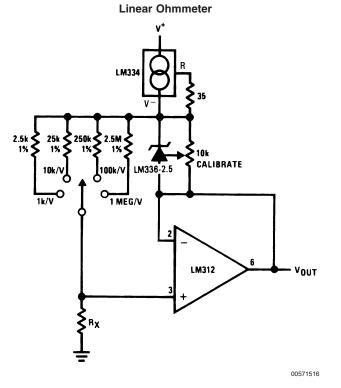
*Does not affect temperature coefficient

 $^{^\}dagger$ Efficiency $\approx 80\%$

Application Hints (Continued)

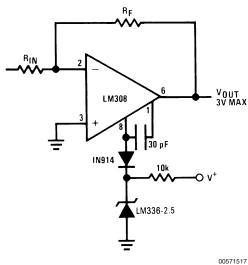
Adjustable Shunt Regulator



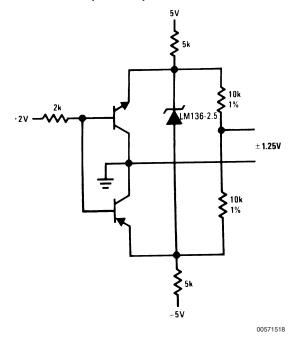


Application Hints (Continued)

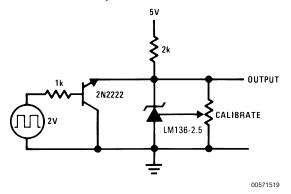
Op Amp with Output Clamped



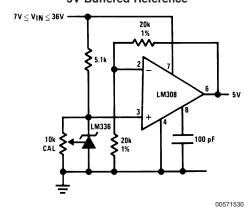
Bipolar Output Reference



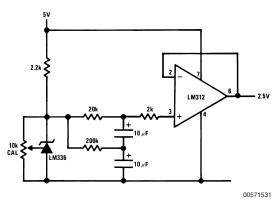
2.5V Square Wave Calibrator



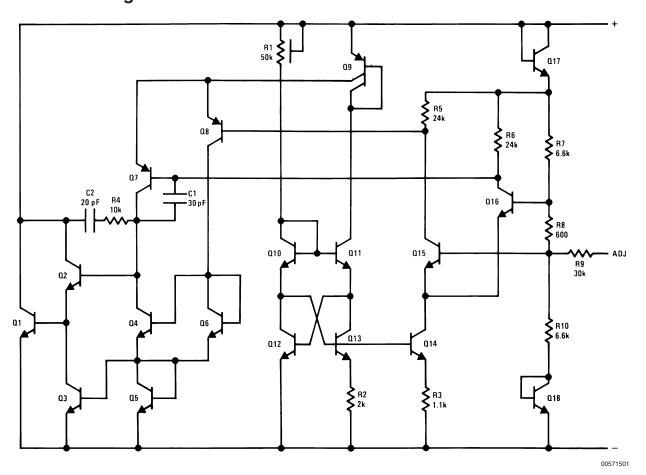
5V Buffered Reference



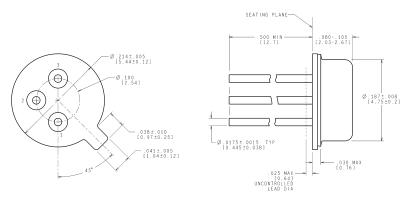
Low Noise Buffered Reference



Schematic Diagram

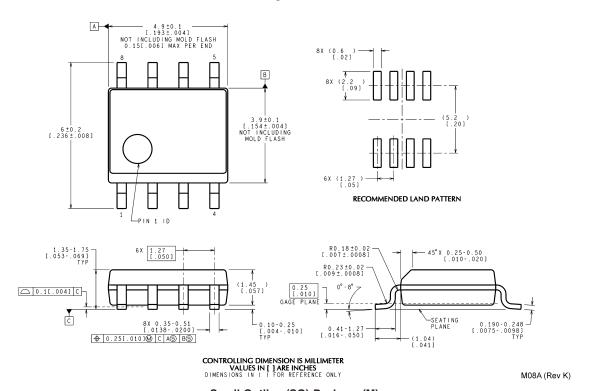


Physical Dimensions inches (millimeters) unless otherwise noted



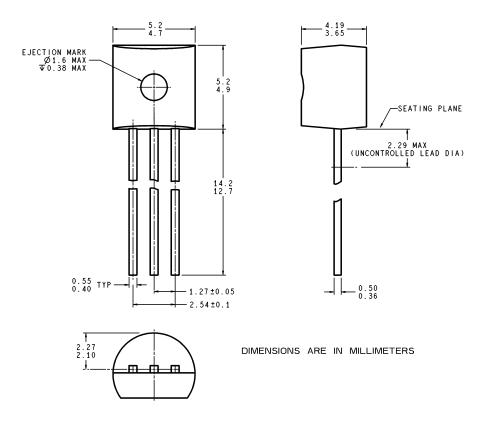
H03H (Rev F)

Order Number LM136H-2.5, LM136H-2.5/883, LM236H-2.5, LM136AH-2.5, LM136AH-2.5/883 or LM236AH-2.5 **NS Package Number H03H**



Small Outline (SO) Package (M) Order Number LM236M-2.5, LM236AM-2.5, LM336M-2.5 or LM336BM-2.5 **NS Package Number M08A**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



TO-92 Plastic Package (Z) Order Number LM336Z-2.5 or LM336BZ-2.5 NS Package Number Z03A

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